

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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HiPerFAST™ IGBT Lightspeed™ Series

IXGH 12N60C



| \mathbf{V}_{CES} | = | 600 V |
|----------------------|---|-------|
| I _{C25} | = | 24 A |
| V _{CE(sat)} | = | 2.7 V |
| t _{fi(typ)} | = | 55 ns |

| Symbol | Test Conditions | Maximum Ratings | | |
|------------------|--|--|------------------------|--|
| V _{CES} | T _J = 25°C to 150°C | 600 | V | |
| V _{CGR} | $T_{_{\mathrm{J}}}$ = 25°C to 150°C; $R_{_{\mathrm{GE}}}$ = 1 M Ω | 600 | V | |
| V _{GES} | Continuous | ±20 | V | |
| V_{GEM} | Transient | ±30 | V | |
| I _{C25} | T _C = 25°C | 24 | Α | |
| I _{C90} | $T_{\rm C} = 90^{\circ}{\rm C}$ | 12 | Α | |
| I _{CM} | $T_{\rm C}$ = 25°C, 1 ms | 48 | Α | |
| SSOA (RBSOA) | V_{GE} = 15 V, T_{VJ} = 125°C, R_{G} = 33 Ω Clamped inductive load, L = 300 μ H | I _{CM} = 24 @ 0.8 V _{CES} | Α | |
| P _c | T _C = 25°C | 100 | W | |
| T _J | | -55 +150 | °C | |
| T _{JM} | | 150 | °C | |
| T _{stg} | | -55 +150 | °C | |
| M _d | Mounting torque with screw M3 Mounting torque with screw M3.5 | 0.45/4 0.55/5 | Nm/lb.in. Nm/lb.in. | |
| Weight | | 6 | g | |
| | ad temperature for soldering 62 in.) from case for 10 s | 300 | °C | |

| G C E | C (TAB) |
|-------|---------|

G = Gate, C = Collector, E = Emitter, TAB = Collector

Features

TO-247

- Very high frequency IGBT
- New generation HDMOS[™] process
- International standard package JEDEC TO-247
- High peak current handling capability

| Symbol | Test Conditions | $(T_J = 25^{\circ}C, \text{ unless } C)$ min. | | istic Va se speci max. | |
|--------------------------|---|---|-----|--------------------------------|----------|
| BV _{CES} | $I_{C} = 250 \ \mu\text{A}, \ V_{GE} = 0 \ \text{V}$ | 600 | | | V |
| $V_{_{\mathrm{GE(th)}}}$ | $I_{\text{C}} = 250 \; \mu\text{A}, \; V_{\text{GE}} = V_{\text{GE}}$ | 2.5 | | 5.0 | V |
| CES | $V_{CE} = 0.8 V_{CES}$ $V_{GE} = 0 V$ | T _J = 25°C T _J = 125°C | | 200 1.5 | μA mA |
| I _{GES} | $V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$ | | | ±100 | nA |
| V _{CE(sat)} | $I_{\rm C} = I_{\rm CE90}, V_{\rm GE} = 15 \text{ V}$ | | 2.1 | 2.7 | V |

Applications

- PFC circuit
- · AC motor speed control
- · DC servo and robot drives
- Switch-mode and resonant-mode power supplies
- High power audio amplifiers

Advantages

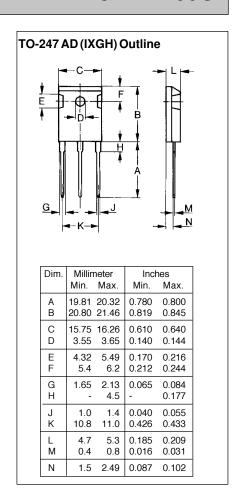
- · Fast switching speed
- · High power density

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| Symbol | Test Conditions Cha $ (T_J = 25^{\circ}C, \text{ unless of min.}) $ | aracteriotherwis | | |
|------------------------------|---|------------------|------|-----|
| g _{fs} | $I_{_{\rm C}}=I_{_{{\rm C90}}};$ $V_{_{{\rm CE}}}=10$ V, Pulse test, t \leq 300 $\mu{\rm s},$ duty cycle \leq 2 % | 11 | | S |
| C _{ies} |) | 860 | | pF |
| C _{oes} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | 64 | | pF |
| C _{res} | J | 15 | | pF |
| $\mathbf{Q}_{_{\mathbf{g}}}$ |) | 32 | | nC |
| \mathbf{Q}_{ge} | $I_{\rm C} = I_{\rm C90}, V_{\rm GE} = 15 \text{ V}, V_{\rm CE} = 0.5 \text{ V}_{\rm CES}$ | 10 | | nC |
| \mathbf{Q}_{gc} |) | 10 | | nC |
| t _{d(on)} | ∫ Inductive load, T _J = 25°C | 20 | | ns |
| t _{ri} | $I_{c} = I_{c90}, V_{GE} = 15 \text{ V}, L = 300 \mu\text{H}$ | 20 | | ns |
| $\mathbf{t}_{d(off)}$ | $V_{CE} = 0.8 V_{CES}, R_G = R_{off} = 18 \Omega$ | 60 | | ns |
| t _{fi} | Remarks: Switching times may increase for V_{CE} (Clamp) > 0.8 V_{CES} , higher T_{\perp} or | 55 | | ns |
| E _{off} | increased R _G | 0.09 | | mJ |
| $\mathbf{t}_{d(on)}$ | \ Inductive load, T ₁ = 125°C | 20 | | ns |
| t _{ri} | $I_{\rm C} = I_{\rm C90}, V_{\rm GF} = 15 \text{ V}, L = 300 \mu\text{H}$ | 20 | | ns |
| E _{on} | $V_{CE} = 0.8 \ V_{CES}, R_{G} = R_{off} = 18 \ \Omega$ | 0.15 | | mJ |
| $\mathbf{t}_{d(off)}$ | Remarks: Switching times may increase for | 85 | 180 | ns |
| t _{fi} | V_{CE} (Clamp) > 0.8 V_{CES} , higher T _J or | 85 | 180 | ns |
| E _{off} | J increased R _g | 0.27 | 0.60 | mJ |
| \mathbf{R}_{thJC} | | | 1.25 | K/W |
| \mathbf{R}_{thCK} | | 0.25 | | K/W |



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